



ELECTRONICS, INC.
44 FARRAND STREET
BLOOMFIELD, NJ 07003
(973) 748-5089
<http://www.nteinc.com>

NTE4049, NTE4049T NTE4050B, NTE4050BT Integrated Circuit CMOS, Hex Buffer/Converter

Description:

The NTE4049/NTE4049T (Inverting) and NTE4050B/NTE4050BT (Non-Inverting) are Hex Buffers and feature logic-level conversion using only one supply voltage (V_{DD}). The input-signal high level (V_{IH}) can exceed the V_{DD} supply voltage when these devices are used for logic level conversions. These devices are intended for use as COS/MOS to DTL/TTL converters and can drive directly two DTL/TTL loads ($V_{DD} = 5V$, $V_{OL} \leq 400mV$, $I_{OL} \geq 3.2mA$).

These devices are available in a standard 16-Lead DIP (NTE4049 and NTE4050B) and SOIC-16 surface mount (NTE4049T and NTE4050BT) type packages.

Features:

- High Sink Current for Driving 2 TTL Loads
- High-to-Low Level Logic Conversion
- Quiescent Current Specified to 20V
- Maximum Input Current of $1\mu A$ at 18V (Full Package Temperature Range)
- High "Sink" and "Source" Current Capability
- 5V, 10V, and 15V Parametric Ratings

Absolute Maximum Ratings:

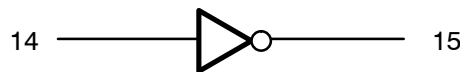
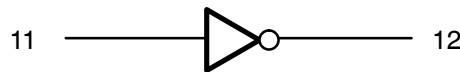
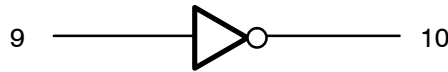
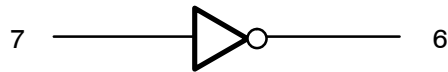
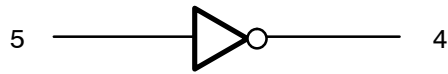
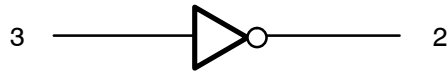
Supply Voltage (Note 1), V_{DD}		-0.5 to 20V
Input Voltage, V_I		-0.5 to $V_{DD} + 0.5V$
DC Input Current (Any One Input), I_I		$\pm 10mA$
Total Power Dissipation, P_{tot}		
Per Package		200mW
Per Output Transistor ($T_{op} = -40^\circ$ to $+85^\circ C$)		100mW
Operating Temperature Range, T_{opr}		-40° to $+85^\circ C$
Storage Temperature Range, T_{stg}		-65° to $+150^\circ C$

Note 1. All voltage values are referred to V_{SS} pin voltage.

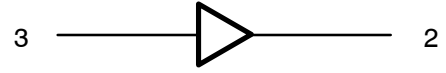
Recommended Operating Conditions:

Supply Voltage, V_{DD}		3 to 18V
Input Voltage (Note 2), V_I		V_{DD} to 18V
Operating Temperature Range, T_{opr}		-40° to $+85^\circ C$

Note 2. The NTE4049/T and NTE4050B/BT have high-to-low-level voltage conversion capability but not low-to-high-level; therefore it is recommended that $V_{IN} \geq V_{DD}$.

NTE4049 & NTE4049T

NC = Pin 13, 16
 V_{SS} = Pin 8
 V_{DD} = Pin 1

NTE4050B and NTE4050BT

NC = Pin 13, 16
 V_{SS} = Pin 8
 V_{DD} = Pin 1

Static Electrical Characteristics: ($T_A = +25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions			Min	Typ	Max	Unit
		V_I (V)	V_O (V)	V_{DD} (V)				
Quiescent Supply Current	I_L	0 to 5	–	5	–	0.02	–	μA
		0 to 10	–	10	–	0.02	–	μA
		0 to 15	–	15	–	0.02	–	μA
		0 to 20	–	20	–	0.04	–	μA
Output High Voltage	V_{OH}	0 to 5	–	5	4.95	–	–	V
		0 to 10	–	10	9.95	–	–	V
		0 to 15	–	15	14.95	–	–	V
Input High Voltage NTE4049, NTE4049T	V_{IH}	–	0.5	5	4	–	–	V
		–	1.0	10	8	–	–	V
		–	2.0	15	12	–	–	V
		–	4.5	5	3.5	–	–	V
		–	9.0	10	7.0	–	–	V
		–	13.5	15	11.0	–	–	V
NTE4050B, NTE4050BT								

Static Electrical Characteristics (Cont'd): ($T_A = +25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions			Min	Typ	Max	Unit
		V_I (V)	V_O (V)	V_{DD} (V)				
Input Low Voltage NTE4049, NTE4049T	V_{IL}	–	4.5	5	–	–	1	V
		–	9.0	10	–	–	2	V
		–	13.0	15	–	–	3	V
		–	0.5	5	–	–	1.5	V
		–	1.0	10	–	–	3.0	V
		–	1.5	15	–	–	4.0	V
Output Drive Current	I_{OH}	0 to 5	2.5	5	–6.0	–6.4	–	mA
		0 to 5	4.6	5	–3.2	–1.6	–	mA
		0 to 10	9.5	10	–0.8	–3.6	–	mA
		0 to 15	13.5	15	–1.8	–12.0	–	mA
Output Sink Current	I_{OL}	0 to 5	0.4	4.5	2.6	5.2	–	mA
		0 to 5	0.4	5	3.2	6.4	–	mA
		0 to 10	0.5	10	8.0	16.0	–	mA
		0 to 15	1.5	15	24.0	48.0	–	mA
Input Leakage Current	I_{IH}, I_{IL}	0 to 18	Any Input	18	–	$\pm 10^{-5}$	± 0.1	μA
Input Capacitance NTE4049, NTE4049T	C_I	Any Input		–	–	15	22.5	pF
NTE4050B, NTE4050BT					–	5	7.5	pF

Note 3. The Noise Margin (NTE4050B/BT Only) for both “1” and “0” level is: 1V min. with $V_{DD} = 5\text{V}$
2V min. with $V_{DD} = 10\text{V}$
2.5V min. with $V_{DD} = 15\text{V}$

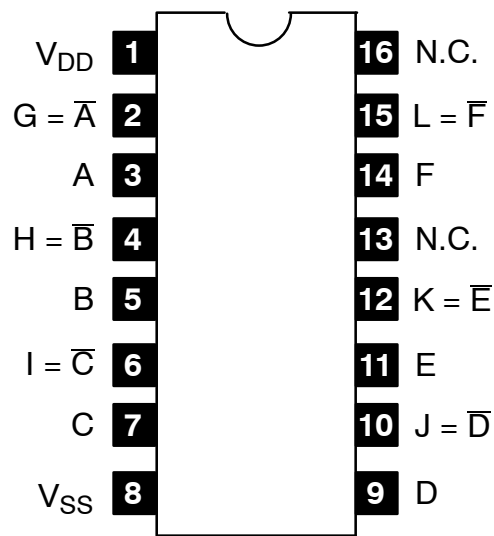
Dynamic Electrical Characteristics: ($T_A = +25^\circ\text{C}$, $C_L = 50\text{pF}$, $R_L = 200\text{k}\Omega$, typical temperature coefficient for all V_{DD} values is $0.3\%/^\circ\text{C}$, all input rise and fall times = 20ns unless otherwise specified)

Parameter	Symbol	Test Conditions		Min	Typ	Max	Unit
		V _I (V)	V _{DD} (V)				
Propagation Delay Time NTE4049, NTE4049T	t _{PLH}	5	5	–	60	120	ns
		10	10	–	32	65	ns
		10	5	–	45	90	ns
		15	15	–	25	590	ns
		15	5	–	45	90	ns
NTE4050B, NTE4050BT		5	5	–	70	140	ns
		10	10	–	40	80	ns
		10	5	–	45	90	ns
		15	15	–	30	60	ns
		15	5	–	40	80	ns

Dynamic Electrical Characteristics (Cont'd): ($T_A = +25^{\circ}\text{C}$, $C_L = 50\text{pF}$, $R_L = 200\text{k}\Omega$, typical temperature coefficient for all V_{DD} values is $0.3\%/^{\circ}\text{C}$, all input rise and fall times = 20ns unless otherwise specified)

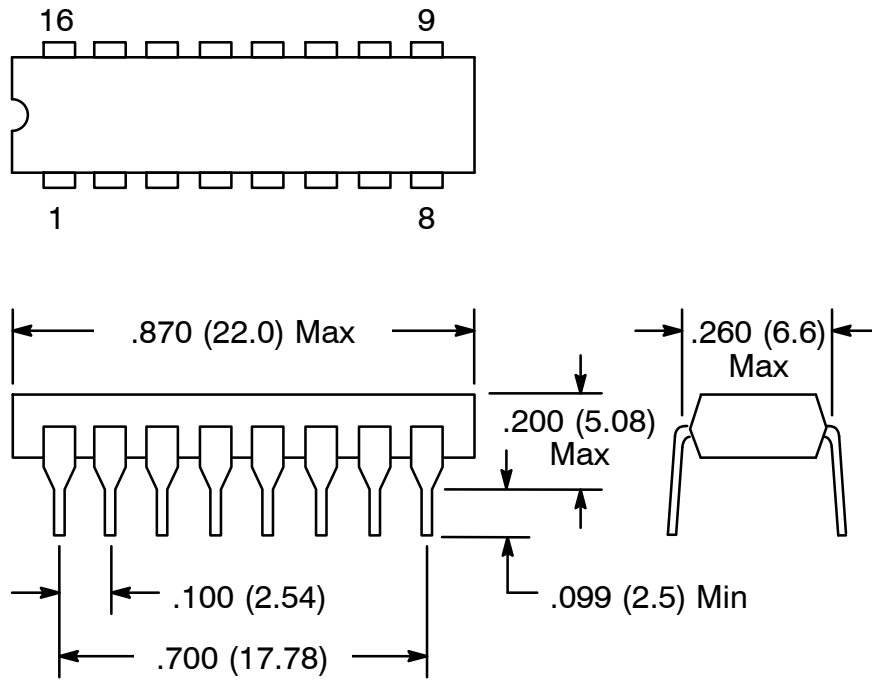
Parameter	Symbol	Test Conditions		Min	Typ	Max	Unit
		V_I (V)	V_{DD} (V)				
Propagation Delay Time NTE4049, NTE4049T NTE4050B, NTE4050BT	t_{PHL}	5	5	–	32	65	ns
		10	10	–	20	40	ns
		10	5	–	15	30	ns
		15	15	–	15	30	ns
		15	5	–	10	20	ns
		5	5	–	55	110	ns
		10	10	–	22	55	ns
		10	5	–	50	100	ns
		15	15	–	15	30	ns
		15	5	–	50	100	ns
Transition Time	t_{TLH}	5	5	–	80	160	ns
		10	10	–	40	80	ns
		15	15	–	30	60	ns
Transition Time	t_{THL}	5	5	–	30	60	ns
		10	10	–	20	40	ns
		15	15	–	15	30	ns

Pin Connection Diagram

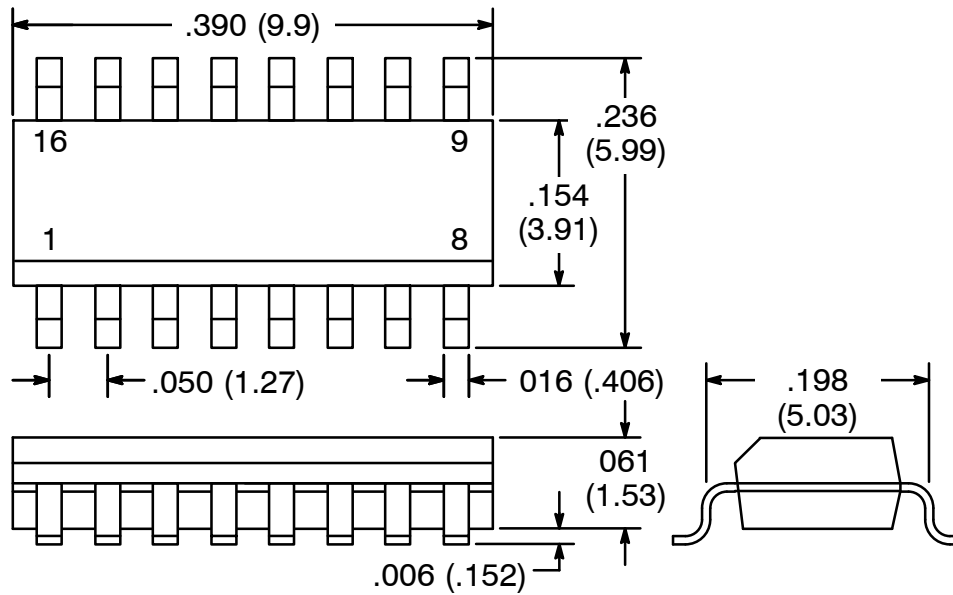


Note: On NTE4050B/BT, Pins 2, 4, 6, 10, 12, and 15 are not inverted.

NTE4049 / NTE4049T



NTE4050B / NTE4050BT



NOTE: Pin1 on Beveled Edge